

	Type	L #	Hits	Search Text	DBs
1	BFS	L1	319780	257/\$.ccis. 438/\$.ccis. 1 and (TFT or TFT-LCD or thin near film near transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	BFS	L2	9461	12 and (fourth near photolithography) 13 and (yoshiaki-kawasaki or nakamura-kazuhiko or inoue-kazunori or yoshida-takuji or nakashima-ken or masutani-yuichi or aoki-hironori).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
3	BFS	L3	65	5 and (TFT or TFT-LCD or (thin near film near transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
4	BFS	L5	1223	6 and (fourth near photolithography) (TFT or TFT-LCD or (thin near film near transistor).ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
5	BFS	L6	104	7 and (TFT or TFT-LCD or (thin near film near transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
6	BFS	L7	5	8 and (fourth near photolithography)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
7	BFS	L8	16779	9 and (fourth near photolithography)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
8	BFS	L9	45	10 and (fourth near photolithography)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
9	BFS	L10	7	11 and (fourth near photolithography)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
10	BFS	L11	44838	12 and (fourth near photolithography)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
11	BFS	L12	91	13 and (fourth near photolithography)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
12	BFS	L13	62	14 and (contact near hole)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB